



93AA66A/B/C, 93LC66A/B/C, 93C66A/B/C

4K Microwire Compatible Serial EEPROM

Device Selection Table

Part Number	Vcc Range	ORG Pin	Word Size	Temp Ranges	Packages
93AA66A	1.8-5.5	No	8-bit	I	P, SN, ST, MS, OT, MC
93AA66B	1.8-5.5	No	16-bit	I	P, SN, ST, MS, OT, MC
93LC66A	2.5-5.5	No	8-bit	I, E	P, SN, ST, MS, OT, MC
93LC66B	2.5-5.5	No	16-bit	I, E	P, SN, ST, MS, OT, MC
93C66A	4.5-5.5	No	8-bit	I, E	P, SN, ST, MS, OT, MC
93C66B	4.5-5.5	No	16-bit	I, E	P, SN, ST, MS, OT, MC
93AA66C	1.8-5.5	Yes	8- or 16-bit	I	P, SN, ST, MS, MC
93LC66C	2.5-5.5	Yes	8- or 16-bit	I, E	P, SN, ST, MS, MC
93C66C	4.5-5.5	Yes	8- or 16-bit	I, E	P, SN, ST, MS, MC

Features:

- Low-Power CMOS Technology
- ORG Pin to Select Word Size for '66C' Version
- 512 x 8-bit Organization 'A' Devices (no ORG)
- 256 x 16-bit organization 'B' Devices (no ORG)
- Self-timed Erase/Write Cycles (including Auto-Erase)
- Automatic Erase All (ERAL) Before Write All (WRAL)
- Power-On/Off Data Protection Circuitry
- Industry Standard 3-Wire Serial I/O
- Device Status Signal (Ready/Busy)
- Sequential Read Function
- 1,000,000 Erase/Write Cycles
- Data Retention > 200 Years
- Pb-free and RoHS Compliant
- Temperature Ranges Supported:
 - Industrial (I) -40°C to +85°C
 - Automotive (E) -40°C to +125°C

Pin Function Table

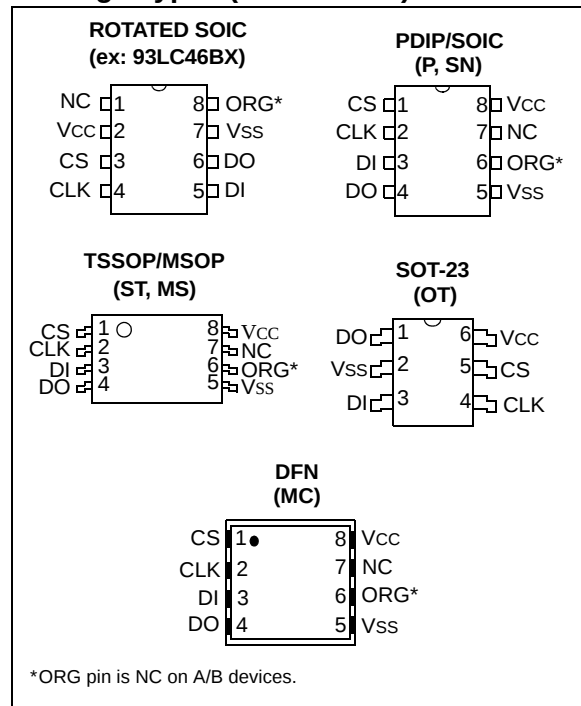
Name	Function
CS	Chip Select
CLK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
Vss	Ground
NC	No internal connection
ORG	Memory Configuration
Vcc	Power Supply

Description:

The Microchip Technology Inc. 93XX66A/B/C devices are 4Kbit low-voltage serial Electrically Erasable PROMs (EEPROM). Word-selectable devices such as the 93AA66C, 93LC66C or 93C66C are dependent upon external logic levels driving the ORG pin to set word size. For dedicated 8-bit communication, the 93XX66A devices are available, while the 93XX66B devices provide dedicated 16-bit communication. Advanced CMOS technology makes these devices ideal for low-power, nonvolatile memory applications. The entire 93XX Series is available in standard packages including 8-lead PDIP and SOIC, and advanced packaging including 8-lead MSOP, 6-lead SOT-23, 8-lead 2x3 DFN and 8-lead TSSOP. All packages are Pb-free (Matte Tin) finish.

93AA66A/B/C, 93LC66A/B/C, 93C66A/B/C

Package Types (not to scale)



93AA66A/B/C, 93LC66A/B/C, 93C66A/B/C

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings^(†)

V _{CC}	7.0V
All inputs and outputs w.r.t. V _{SS}	-0.6V to V _{CC} +1.0V
Storage temperature	-65°C to +150°C
Ambient temperature with power applied.....	-40°C to +125°C
ESD protection on all pins	≥ 4 kV

† **NOTICE:** Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: DC CHARACTERISTICS

All parameters apply over the specified ranges unless otherwise noted.			Industrial (I): TA = -40°C to +85°C, V _{CC} = +1.8V to +5.5V Automotive (E): TA = -40°C to +125°C, V _{CC} = +2.5V to +5.5V				
Param. No.	Symbol	Parameter	Min	Typ	Max	Units	Conditions
D1	V _{IH1}	High-level input voltage	2.0	—	V _{CC} +1	V	V _{CC} ≥ 2.7V
	V _{IH2}		0.7 V _{CC}	—	V _{CC} +1	V	V _{CC} < 2.7V
D2	V _{IL1}	Low-level input voltage	-0.3	—	0.8	V	V _{CC} ≥ 2.7V
	V _{IL2}		-0.3	—	0.2 V _{CC}	V	V _{CC} < 2.7V
D3	V _{OL1}	Low-level output voltage	—	—	0.4	V	I _{OL} = 2.1 mA, V _{CC} = 4.5V
	V _{OL2}		—	—	0.2	V	I _{OL} = 100 μA, V _{CC} = 2.5V
D4	V _{OH1}	High-level output voltage	2.4	—	—	V	I _{OH} = -400 μA, V _{CC} = 4.5V
	V _{OH2}		V _{CC} - 0.2	—	—	V	I _{OH} = -100 μA, V _{CC} = 2.5V
D5	I _{LI}	Input leakage current	—	—	±1	μA	V _{IN} = V _{SS} or V _{CC}
D6	I _{LO}	Output leakage current	—	—	±1	μA	V _{OUT} = V _{SS} or V _{CC}
D7	C _{IN} , C _{OUT}	Pin capacitance (all inputs/ outputs)	—	—	7	pF	V _{IN} /V _{OUT} = 0V (Note 1) TA = 25°C, F _{CLK} = 1 MHz
D8	I _{CC} write	Write current	—	—	2	mA	F _{CLK} = 3 MHz, V _{CC} = 5.5V
			—	500	—	μA	F _{CLK} = 2 MHz, V _{CC} = 2.5V
D9	I _{CC} read	Read current	—	—	1	mA	F _{CLK} = 3 MHz, V _{CC} = 5.5V
			—	—	500	μA	F _{CLK} = 2 MHz, V _{CC} = 3.0V
			—	100	—	μA	F _{CLK} = 2 MHz, V _{CC} = 2.5V
D10	I _{CCS}	Standby current	—	—	1	μA	I – Temp
			—	—	5	μA	E – Temp CLK = Cs = 0V ORG = DI = V _{SS} or V _{CC} (Note 2) (Note 3)
D11	V _{POR}	V _{CC} voltage detect 93AA66A/B/C, 93LC66A/B/C 93C66A/B/C	—	1.5V	—	V	(Note 1)
			—	3.8V	—	V	

Note 1: This parameter is periodically sampled and not 100% tested.

2: ORG pin not available on 'A' or 'B' versions.

3: Ready/Busy status must be cleared from DO; see **Section 3.4 "Data Out (DO)"**.

93AA66A/B/C, 93LC66A/B/C, 93C66A/B/C

TABLE 1-2: AC CHARACTERISTICS

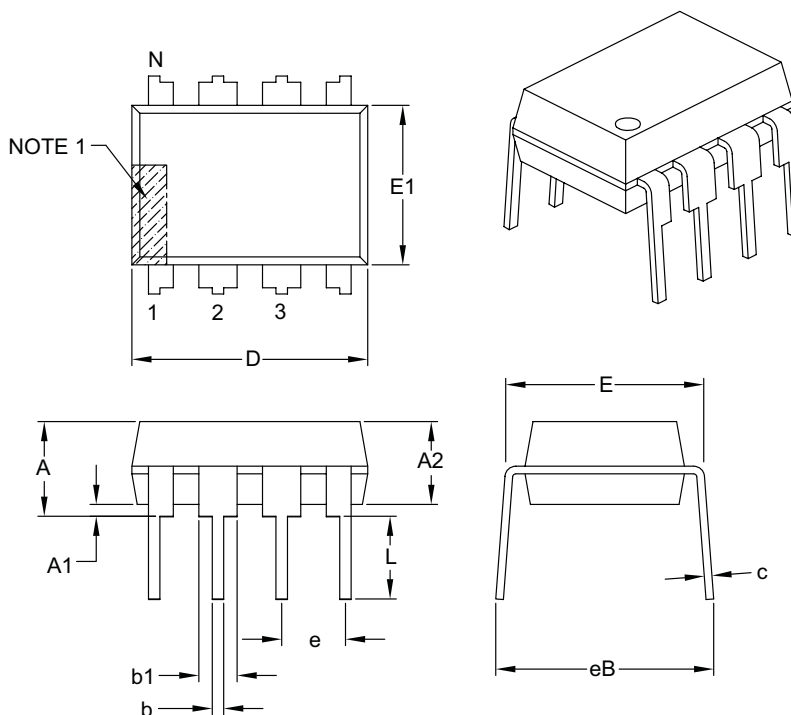
All parameters apply over the specified ranges unless otherwise noted.			Industrial (I): TA = -40°C to +85°C, VCC = +1.8V to +5.5V Automotive (E): TA = -40°C to +125°C, VCC = +2.5V to +5.5V			
Param. No.	Symbol	Parameter	Min	Max	Units	Conditions
A1	FCLK	Clock frequency	—	3 2 1	MHz MHz MHz	4.5V ≤ VCC < 5.5V, 93XX66C only 2.5V ≤ VCC < 5.5V 1.8V ≤ VCC < 2.5V
A2	TCKH	Clock high time	200 250 450	—	ns ns ns	4.5V ≤ VCC < 5.5V, 93XX66C only 2.5V ≤ VCC < 5.5V 1.8V ≤ VCC < 2.5V
A3	TCKL	Clock low time	100 200 450	—	ns ns ns	4.5V ≤ VCC < 5.5V, 93XX66C only 2.5V ≤ VCC < 5.5V 1.8V ≤ VCC < 2.5V
A4	TcSS	Chip Select setup time	50 100 250	—	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A5	TcSH	Chip Select hold time	0	—	ns	1.8V ≤ VCC < 5.5V
A6	TcSL	Chip Select low time	250	—	ns	1.8V ≤ VCC < 5.5V
A7	TDIS	Data input setup time	50 100 250	—	ns ns ns	4.5V ≤ VCC < 5.5V, 93XX66C only 2.5V ≤ VCC < 5.5V 1.8V ≤ VCC < 2.5V
A8	TDIH	Data input hold time	50 100 250	—	ns ns ns	4.5V ≤ VCC < 5.5V, 93XX66C only 2.5V ≤ VCC < 5.5V 1.8V ≤ VCC < 2.5V
A9	TPD	Data output delay time	—	200 250 400	ns ns ns	4.5V ≤ VCC < 5.5V, CL = 100 pF 2.5V ≤ VCC < 4.5V, CL = 100 pF 1.8V ≤ VCC < 2.5V, CL = 100 pF
A10	TCZ	Data output disable time	—	100 200	ns ns	4.5V ≤ VCC < 5.5V, (Note 1) 1.8V ≤ VCC < 4.5V, (Note 1)
A11	Tsv	Status valid time	—	200 300 500	ns ns ns	4.5V ≤ VCC < 5.5V, CL = 100 pF 2.5V ≤ VCC < 4.5V, CL = 100 pF 1.8V ≤ VCC < 2.5V, CL = 100 pF
A12	TWC	Program cycle time	—	6	ms	Erase/Write mode (AA and LC versions)
A13	TWC		—	2	ms	Erase/Write mode (93C versions)
A14	TEC		—	6	ms	ERAL mode, 4.5V ≤ VCC ≤ 5.5V
A15	TWL		—	15	ms	WRAL mode, 4.5V ≤ VCC ≤ 5.5V
A16	—	Endurance	1M	—	cycles	25°C, VCC = 5.0V, (Note 2)

Note 1: This parameter is periodically sampled and not 100% tested.

2: This application is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance™ Model, which may be obtained from Microchip's web site at

93AA66A/B/C, 93LC66A/B/C, 93C66A/B/C

8-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N	8		
Pitch	e	.100 BSC		
Top to Seating Plane	A	—	—	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	—	—
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	—	—	.430

Notes:

1. Pin 1 visual index feature may vary, but must be located with the hatched area.
2. § Significant Characteristic.
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

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PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	X	X	X	XXX	X
Device	Pinout	Tape & Reel	Temperature Range	Package	Lead Finish
Device: 93AA66A: 4K 1.8V Microwire Serial EEPROM 93AA66B: 4K 1.8V Microwire Serial EEPROM 93AA66C: 4K 1.8V Microwire Serial EEPROM w/ORG 93LC66A: 4K 2.5V Microwire Serial EEPROM 93LC66B: 4K 2.5V Microwire Serial EEPROM 93LC66C: 4K 2.5V Microwire Serial EEPROM w/ORG 93C66A: 4K 5.0V Microwire Serial EEPROM 93C66B: 4K 5.0V Microwire Serial EEPROM 93C66C: 4K 5.0V Microwire Serial EEPROM w/ORG					
Pinout: Blank = Standard pinout X = Rotated pinout					
Tape & Reel: Blank = Standard packaging T = Tape & Reel					
Temperature Range: I = -40°C to +85°C E = -40°C to +125°C					
Package: MS = Plastic MSOP (Micro Small outline, 8-lead) OT = SOT-23, 6-lead (Tape & Reel only) P = Plastic DIP (300 mil body), 8-lead SN = Plastic SOIC (150 mil body), 8-lead ST = TSSOP, 8-lead MC = 2x3 DFN, 8-lead					
Examples: a) 93AA66C-I/MS: 4K, 512x8 or 256x16 Serial EEPROM, MSOP package, 1.8V b) 93AA66B-I/MS: 4K, 256x16 Serial EEPROM, MSOP package, 1.8V c) 93AA66AT-I/OT: 4K, 512x8 Serial EEPROM, SOT-23 package, tape and reel, 1.8V d) 93AA66CT-I/MS: 4K, 512x8 or 256x16 Serial EEPROM, MSOP package, tape and reel, 1.8V a) 93LC66A-I/MS: 4K, 512x8 Serial EEPROM, MSOP package, 2.5V b) 93LC66BT-I/OT: 4K, 256x16 Serial EEPROM, SOT-23 package, tape and reel, 2.5V c) 93LC66B-I/MS: 4K, 256x16 Serial EEPROM, MSOP package, 2.5V a) 93C66B-I/MS: 4K, 256x16 Serial EEPROM, MSOP package, 5.0V b) 93C66C-I/MS: 4K, 512x8 or 256x16 Serial EEPROM, MSOP package, 5.0V c) 93C66AT-I/OT: 4K, 512x8 Serial EEPROM, SOT-23 package, tape and reel, 5.0V					